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# Quadratic Equation Based Solar Panel Modelling Using MOSFET Transistor

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## Abstract

- In this presentation, we present a newer dataset generating technique such that a single tool like Matlab can generate the data.
- This generated dataset will be used by ML algorithm to train solar powered drones for effective power management during the search and rescue mission.
- For achieving this, it is essential to remove the non-linearity from the analytical model of the PV module that typically uses 1-diode, 2-diode, or 3-diode.
- The first step is to transform the current source into voltage source.
- Later, the cause of the non-linearity is the presence of the diode in the equivalent PV cell model is replaced with Metal Oxide Semiconductor Field Effect Transistor (MOSFET) based diode.
- The accuracy of the analytical model is verified by using SPICE simulation.

## Introduction

- For search and rescue missions, drones are increasingly playing a pivotal role.
- To make drones effective in rapidly evolving situations, it is essential for them to be aerial for a longer time and possess the ability to switch between cross-functional roles in real-time.
- All this can be achieved by powering a drone with a reconfigurable solar panel.
- For the reconfigurable solar panel to be an effective power source for drones for various missions, it is crucial for them to be controlled by intelligent machine learning (ML) algorithms.
- For this purpose, there is a dataset requirement that can train the ML algorithm in different operating conditions.
- Hence, to create a effective dataset that covers all possible operating conditions, multiple tools such as SPICE simulator, and python is used.
- Using of multiple tools for generating a vast dataset will put lot of strain on computing system.
- In this presentation, we are simplifying it by modifying the equivalent solar cell model such that a single tool like Matlab can be able to generate the dataset.

## Methodology

### Typical Solar Cell Modelling:

Where,

$I_{ph}$  = Photon Current

$I_D$  = Diode Current

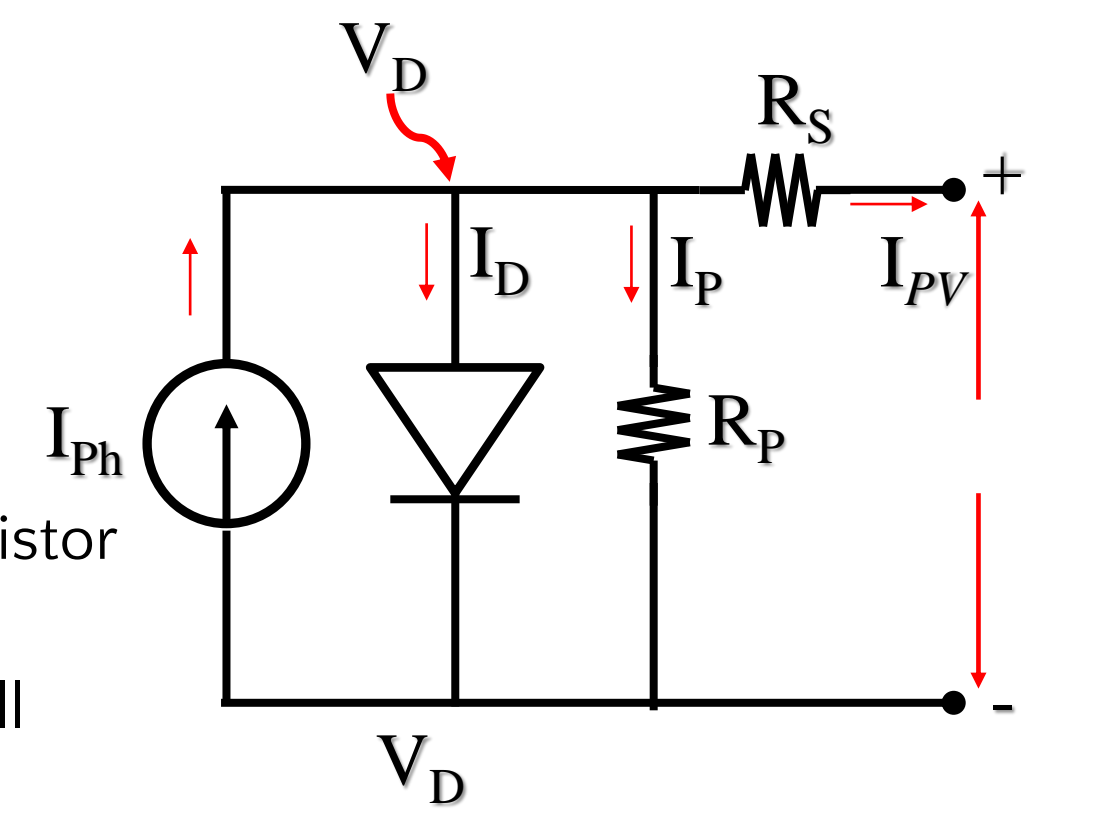
$R_p$  = Shunt Resistance

$I_p$  = Current Across the Shunt Resistor

$R_s$  = Series Resistance

$I_{PV}$  = Current Generated by PV Cell

$V_{PV}$  = Voltage Across a PV Cell



### Proposed Solar Cell Modelling

Using Kirchhoff's Current Law

$$I = I_D + I_{PV} \quad (1)$$

$$V_D = V_{PV} - IR_p$$

$$V_D = I_{ph}R_p - (I_D + I_{PV})R_p \quad (2)$$

$$V_D = V_{PV} + R_s I_{PV} \quad (3)$$

Equating (2) and (3) gives

$$V_{PV} + R_s I_{PV} = I_{ph}R_p - I_D R_p - I_{PV} R_p$$

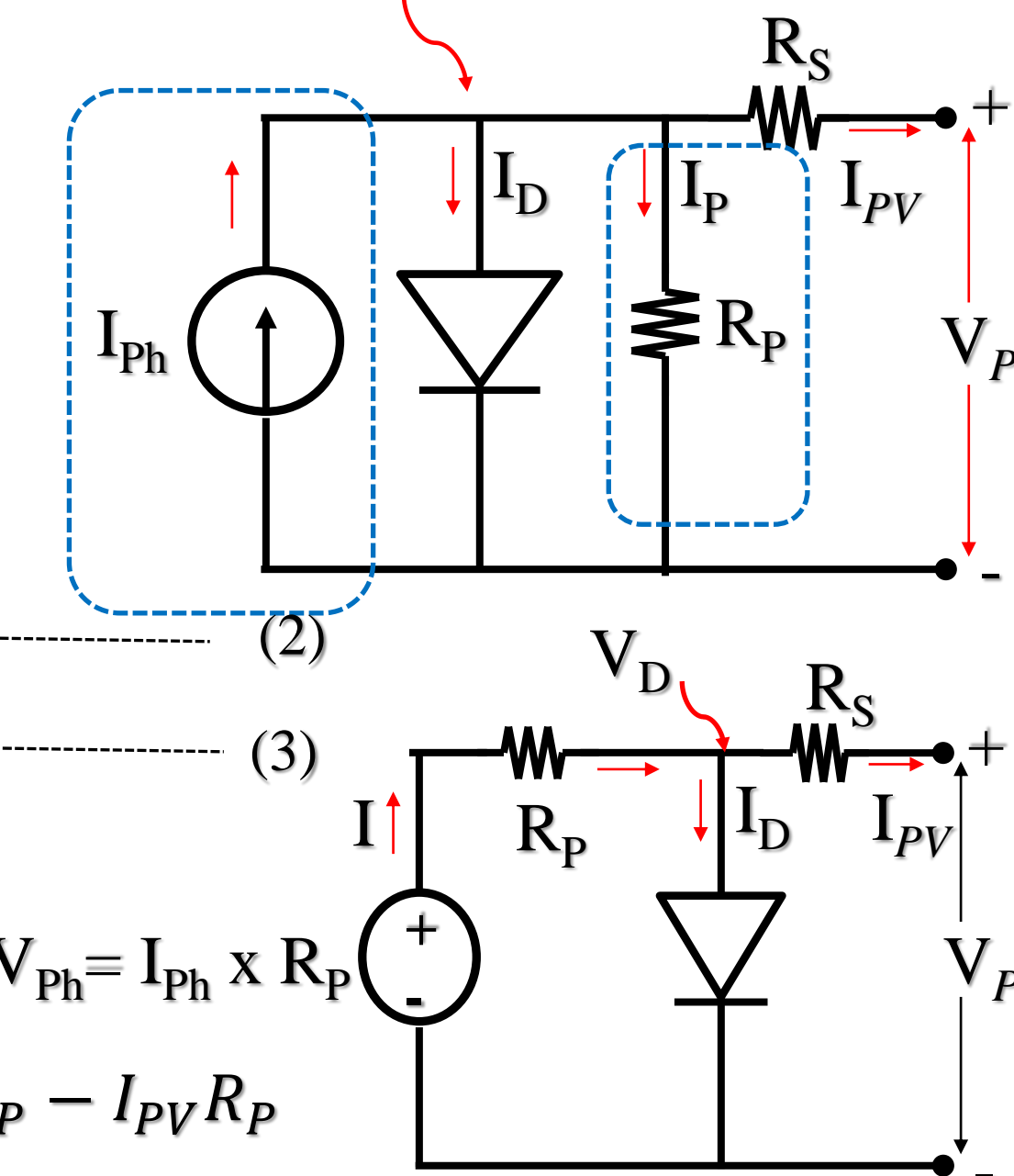
$$I_{PV}(R_s + R_p) = I_{ph}R_p - I_D R_p - V_{PV}$$

$$I_{PV} = \frac{1}{(R_s + R_p)} (I_{ph}R_p - I_D R_p - V_{PV}) \quad (4)$$

Presence of  $I_D$  is cause of non-linearity in the IPV mathematical modelling.

$$I_D = I_s (e^{\frac{V_D}{nV_t}} - 1) \quad (5)$$

Hence, the diode can be replaced with NMOS based diode by shorting the gate and drain terminal.



## Methodology - continue

### Proposed MOSFET based Solar Cell Model

Where,

$I_M$  = Current across the NMOS

$K_N$  = Process Transconductance

$W$  = Width of NMOS

$L$  = Length of NMOS

$V_{GS}$  = Voltage between gate and source terminal

$V_{DS}$  = Voltage between gate and source terminal

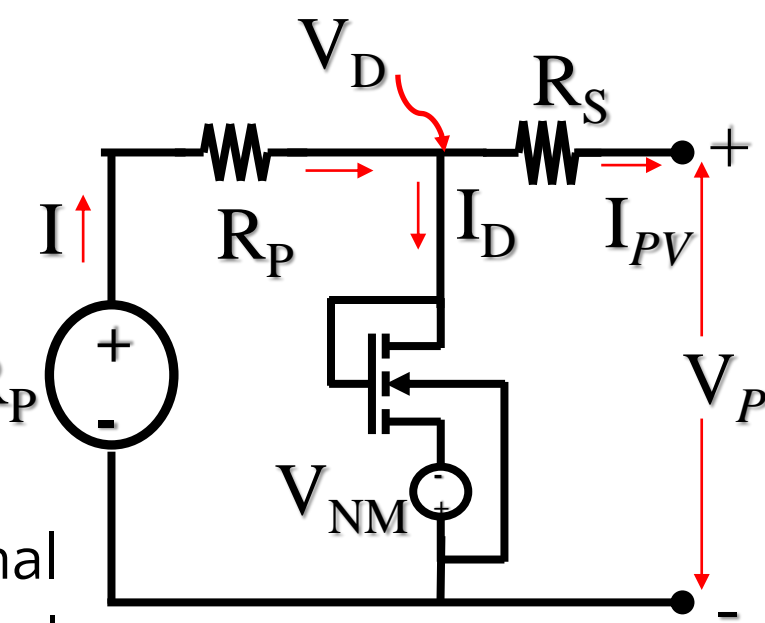
$V_{tn}$  = Threshold voltage of NMOS transistor

$\lambda$  = Channel Length Modulation

$$I_{PV} = \frac{-b \pm \sqrt{b^2 - 4ac}}{2a} \quad a = \frac{K_n R_s^2 (W/L)}{2}$$

$$b = R_p + R_s + K_n R_s \left(\frac{W}{L}\right) (V_{PV} - V_{tn})$$

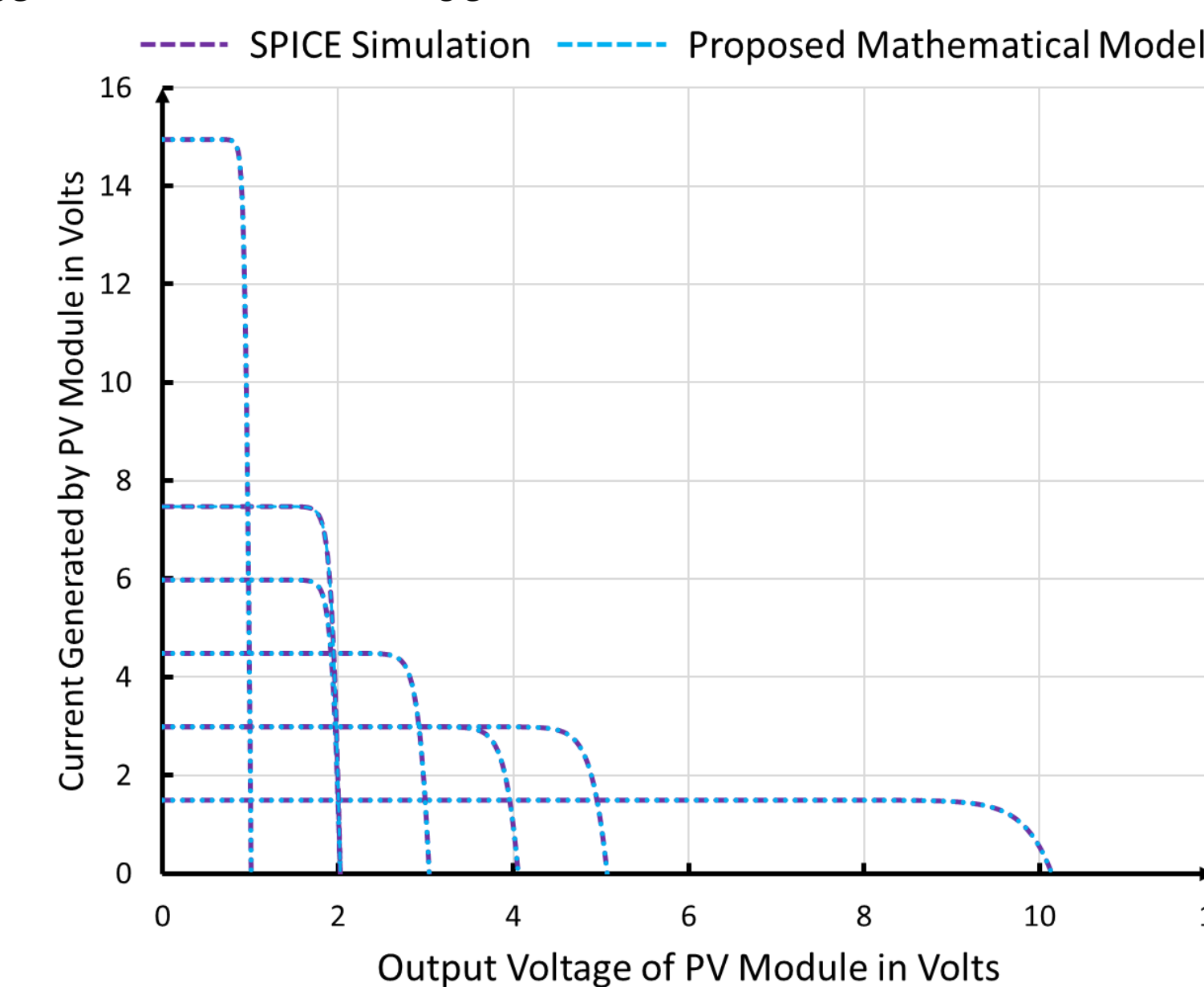
$$c = \frac{K_n}{2} \left(\frac{W}{L}\right) V_{PV}^2 - \frac{K_n}{2} \left(\frac{W}{L}\right) V_{PV} V_{tn} + V_{PV} + \frac{K_n}{2} \left(\frac{W}{L}\right) V_{tn}^2 - I_{ph} R_p$$



## Results

Type of PV Cells (AMO Sunlight (135.3mW/cm<sup>2</sup>) GaAs/Ge Single Junction Solar Cells.

$J_{SC} = 30.5 \text{ mA/cm}^2$ ,  $V_{OC} = 1.025V$ , Area of PV Cell = 7 cm x 7 cm.



## Conclusion

- The use of MOSFET to replace diode in the equivalent solar cells was able to simplify the modelling technique.
- The MOSFET based diode resulted in transforming the non-linear equation for computing output current,  $I_{PV}$ , into quadratic equation.
- Parameter extraction from solar cells and modules is very challenging task.
- The proposed technique will simplify the process.
- Same is the case with multi-junction solar cells and modules. The proposed technique will make the modeling for them much easier.
- The large-scale solar farm are getting much more popular over the years. Due to simplicity of the proposed technique this will make the solar farm simulation less resource intensive.
- Couple of other solar panel modelling technique where MOSFET transistors were used. In future, we will compare the performance of proposed technique with other published work.

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